

5C3712

U.S. UTILITY Patent Application

**PATENT NUMBER and
ISSUE DATE**

APPL NUM 10091193	FILING DATE 03/05/2002	CLASS 257	SUBCLASS	GAU 2856 2811	EXAMINER Tian, Tan
**APPLICANTS: Chen Howard; Hsu Louis; Wang Li-Kong;					
**CONTINUING DATA VERIFIED: THIS APPLICATION IS A CIP OF 09/579,044 05/26/2000 <i>yes / 11</i>					
FOREIGN APPLICATIONS VERIFIED: <i>no / 11</i>					
PG-PUB DO NOT PUBLISH <input type="checkbox"/>		RESCIND <input type="checkbox"/>			
Foreign priority claimed 35 USC 119 conditions met Verified and Acknowledged Examiners's initials <i>TT</i>		<input type="checkbox"/> yes <i>no</i> <input type="checkbox"/> yes <i>no</i>		ATTORNEY DOCKET NO YOR91999-0420-US2	
TITLE : Semiconductor high dielectric constant decoupling capacitor structures and process for fabrication					
U.S. DEPT. OF COMMERCE PAT. & TM. OFF. 4150 Rev. 12/94					

NOTICE OF ALLOWANCE MAILED		Assistant Examiner	CLAIMS ALLOWED		
			Total Claims		Print Claim for O.G
ISSUE FEE		Primary Examiner	DRAWING		
Amount Due	Date Paid		Sheets Drwg.	Figs.Drwg.	Print Fig.
<input type="checkbox"/> TERMINAL DISCLAIMER		PREPARED FOR ISSUE	Application Examiner		
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